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PART NUMBER 0783L-21A ITEM NAME 783 NM SLM LASER (VBG DIODE; FREE-SPACE)

PRODUCT DATASHEET



DESCRIPTION

783 nm SLM laser is designed for Shifted Excitation Raman Difference Spectroscopy (SERDS). This laser is used together with a 785 nm as a matched pair of identical excitation sources having central wavelength peaks separated by 2 nm apart. This separation is quite universal and suitable for most spectrometers. It is recommended to combine the two laser beams into a single optical path using a polarizer and then apply the laser lens clean-up filter. Another approach is to use Volume Bragg Grating based filters for coupling the beams together and cleaning-up the lines at the same time.

Note:

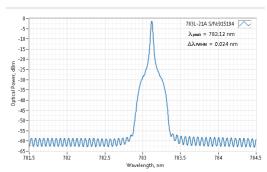
In optical systems with strong back-reflections (e.g. more than 10%), the laser must be protected by using an optical isolator with at least 20 dB isolation. Typical applications include interferometry, confocal microscopy (especially working with reflective samples), etc. Failure to comply with these requirements will render the warranty void for cases of COD (Catastrophic Optical Damage) of laser diode facets.

SPECIFICATIONS

Specifications updated: 30 September 2020

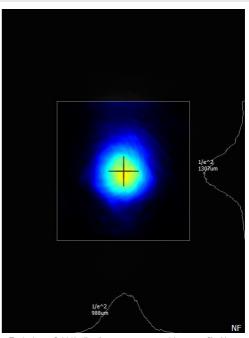
Parameter	Minimum Value	Typical Value	Maximum Value
Central Wavelength, nm	782.9	783	783.1
Longitudinal modes	-	Single	-
Spectral line width FWHM, pm	-	0.1 1	1
Output power, mW	-	110 ²	120
Side-mode suppression ratio (SMSR), dB	40	50	60
Power stability, % (RMS, 8 hrs)	0.01	0.03 3	0.25
Power stability, % (peak-to-peak, 8 hrs)	0.05	0.15 4	0.5
Noise, % (RMS, 20 Hz to 20 MHz)	0.05	0.25 ⁵	0.6
Transversal modes	-	TEM00	-
Beam width (1/e2), mm	-	1 6	1.7
Beam height (1/e2), mm	-	1.2	1.9
Horizontal beam divergence, mrad	-	1.5	1.8
Vertical beam divergence, mrad	-	0.8	1.6
M ² horizontal axis	-	1.2	1.4
M ² vertical axis	-	1.3	1.6
M ² effective	-	1.3	1.6
Polarization direction	-	Horizontal ⁷	-
Polarization contrast	1000	2000	5000
Control interface type	-	UART 8	-
Operation mode	-	APC (CW	-
Modulation bandwidth, MHz	-	10 ⁹	-
Input voltage, VDC	4.8	5	5.3
External power supply requirement	-	+5 V DC, 1.5 A	-

TYPICAL SPECTRUM



Typical spectrum of 0783 nm diode laser. Measured with 20 pm resolution.

TYPICAL NEAR FIELD



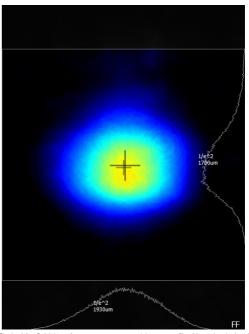
Typical near field (0.45 m from output aperture) beam profile. Noncircularized beam of a 0783 nm direct diode laser.

Dimensions, mm	-	50 x 30 x 18 ¹⁰	-
Beam height from the base, mm	9.9	10.4	10.9
Heat-sinking requirement, °C/W	-	1	-
Optimum heatsink temperature, °C	15	20	30
Warm up time, mins (cold start)	0.2	1	2
Temperature stabilization	-	Internal TEC	-
Overheat protection	-	Yes	-
Storage temperature, °C (non-condensing)	-10	-	50
Net weight, kg	0.1	0.12	0.14
Max. power consumption, W	0.4	2	10
Warranty, months (op. hrs)	-	14 (10000) ¹¹	-
RoHS	-	Yes	-
CE compliance	-	- General Product Safety Directive (GPSD) 2001/95/EC - (EMC) Directive 2004/108/EC	-
Laser Safety Class	-	3B	-
OEM lasers are not compliant with	-	IEC60825- 1:2014 (compliant using additional accessories)	-
Country of origin	-	Lithuania	-

¹ Measured with a scanning Fabry-Perot interferometer having 7.5 Mhz resolution, with scanning frequency of about 10 Hz. Interferometer testing is not provided for each laser being manufactured, the standard test is OSA measurement with 10-20 pm resolution instead.

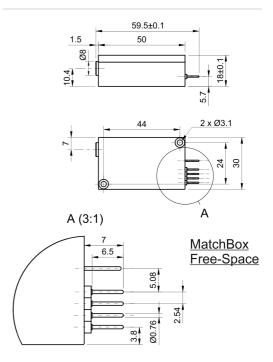
Note: Product specifications are subject to change without prior notice to improve reliability, function or design or otherwise.

TYPICAL FAR FIELD



Typical far field (1 m from output aperture) beam profile. Non-circularized beam of a 0783 nm direct diode laser.

DRAWING



²The output power of SLM lasers shall not be tuned and SLM performance is not guaranteed at power ratings other than factory preset. However, the power setting capability is not disabled. External attenuators are recommended instead.

³The long term power test is carried out at constant laser body temperature (+/-0.1 °C) using an optical power meter with an input bandwidth of 10 Hz. The actual measurement rate has a period of about 20 seconds to 1 minute.

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⁵ Noise level is measured with a fast photodiode connected to an oscilloscope. The overall system bandwidth is from 2 kHz to 20 MHz

 $^{^{\}rm 6}\,\text{Beam}$ width and height are measured at 0.45 m from output aperture.

 $^{^{7} \, \}mathrm{For} \, \mathrm{lasers} \, \mathrm{without} \, \mathrm{integrated} \, \mathrm{optical} \, \mathrm{isolators}.$

⁸ Break-out-boxes AM-C8 and AM-C3 can be used for conversion of UART communication to either USB or RS232.

⁹TTL digital modulation up to 10 MHz.

¹⁰ Excluding control interface pins and an output window/fiber assembly.

¹¹ Whichever occurs first. The laser has an integrated operational hours counter.